

# isc N-Channel MOSFET Transistor

## **R6504ENJ**

### **FEATURES**

- Drain Current –I<sub>D</sub>= 4.0A@ T<sub>C</sub>=25℃
- · Drain Source Voltage-: V<sub>DSS</sub>=650V(Min)
- Static Drain-Source On-Resistance
- :  $R_{DS(on)} = 1.05 \Omega$  (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

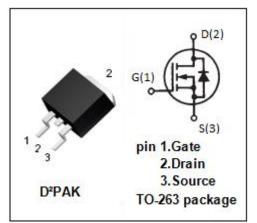
· Designed for use in switch mode power supplies and general purpose applications.

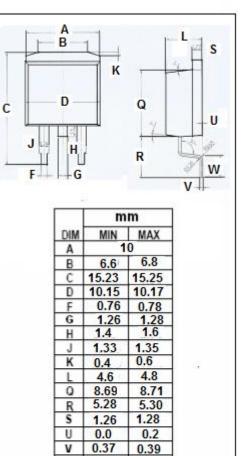
ADSOLUTE MAXIMUM RATINGS(Ta-25 C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	rain-Source Voltage 650				
$V_{GS}$	Gate-Source Voltage-Continuous	ource Voltage-Continuous ±20				
ID	Drain Current-Continuous 4.0		А			
I <sub>DM</sub>	Drain Current-Single Pluse 12		А			
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C 58		W			
TJ	Max. Operating Junction Temperature	-55~150	°C			
T <sub>stg</sub>	Storage Temperature	-55~150	°C			

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

### **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.2	°C/W





٧ W

2.80

2.82



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	650		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =130uA	2	4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =1.5A		1.05	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0@T <sub>J</sub> =125°C		100 1000	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 4A; V <sub>GS</sub> = 0		1.5	V

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